



P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

| BV _{DSS} | R _{DS(ON)} Max | I _D Max T _A = +25°C |
|-------------------|--------------------------------|--|
| 001/ | 62mΩ @ V _{GS} = -4.5V | -3.8A |
| -20V | 90mΩ @ V _{GS} = -2.5V | -3.1A |

Description and Applications

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}), yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- Battery Charging
- Power Management Functions
- DC-DC Converters
- Portable Power Adaptors

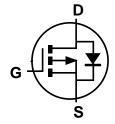
Features and Benefits

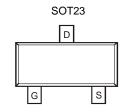
- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen- and Antimony-Free. "Green" Device (Note 3)

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Annealed over Copper Lead-Frame.
 Solderable per MIL-STD-202, Method 208 @3
- Terminals Connections: See Diagram Below
- Weight: 0.009 grams (Approximate)







Top View

Internal Schematic

Top View

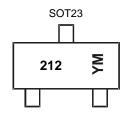
Ordering Information (Note 4)

| Part Number | Case | Packaging |
|-------------|-------|--------------------|
| DMP2120U-7 | SOT23 | 3,000/Tape & Reel |
| DMP2120U-13 | SOT23 | 10,000/Tape & Reel |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



212 = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: H = 2020) M or \overline{M} = Month (ex: 9 = September)

Date Code Key

| Year | 2017 | ~ | | 2020 | 20 | 021 | 2022 | | 2023 | 2024 | | 2025 |
|-------|------|-----|-----|------|-----|-----|------|-----|------|------|-----|------|
| Code | Е | 7 | | Н | | | J | | K | L | | М |
| Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 0 | N | D |



Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

| Characteristic | | Symbol | Value | Unit | |
|---|-------------|-----------------|----------------|------|---|
| Drain-Source Voltage | V_{DSS} | -20 | V | | |
| Gate-Source Voltage | V_{GSS} | ±8 | V | | |
| Continuous Drain Current (Note 6) $V_{GS} = -4.5V$ Steady $T_A = +25^{\circ}C$ State $T_A = +70^{\circ}C$ | | I _D | -3.8 -3.0 | А | |
| Maximum Continuous Body Diode Forward Curr | ent (Note 6 | 6) | I _S | -1.3 | Α |
| Pulsed Drain Current (10µs Pulse, Duty Cycle = | 1%) | I _{DM} | -20 | Α | |

Thermal Characteristics

| Characteristic | Symbol | Value | Unit | | |
|--|--------------|------------------|-------------|------|--|
| Total Power Dissipation (Note 5) | P_{D} | 0.8 | W | | |
| Thermal Resistance, Junction to Ambient (Note 5) | Steady State | D | 163 | °C/W | |
| Thermal Resistance, Junction to Ambient (Note 3) | t<10s | $R_{\theta JA}$ | 114 | C/VV | |
| Total Power Dissipation (Note 6) | | P_{D} | 1.3 | W | |
| Thermal Resistance, Junction to Ambient (Note 6) | Steady State | P | 94 | °C/W | |
| Thermal Resistance, Junction to Ambient (Note 6) | t<10s | R _{0JA} | 66 | C/VV | |
| Operating and Storage Temperature Range | | $T_{J,}T_{STG}$ | -55 to +150 | °C | |

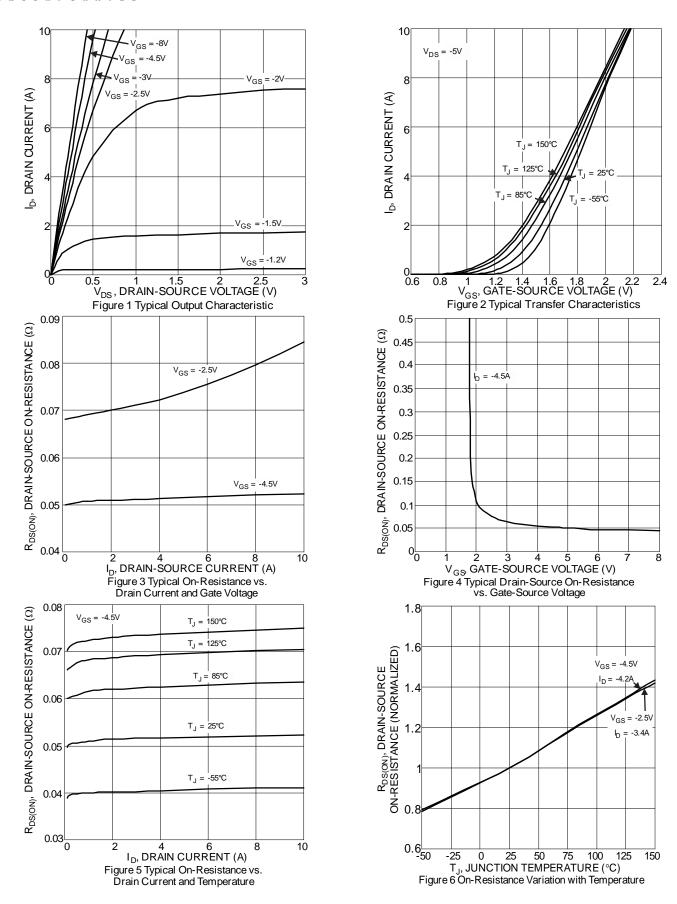
Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition |
|--|---------------------|------|------|------|------|---|
| OFF CHARACTERISTICS (Note 7) | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | -20 | _ | _ | V | $V_{GS} = 0V, I_D = -250\mu A$ |
| Zero Gate Voltage Drain Current T _J = +25°C | I _{DSS} | _ | _ | -1.0 | μΑ | V _{DS} = -20V, V _{GS} = 0V |
| Gate-Source Leakage | I _{GSS} | _ | _ | ±100 | nA | $V_{GS} = \pm 8V$, $V_{DS} = 0V$ |
| ON CHARACTERISTICS (Note 7) | - | | | | | |
| Gate Threshold Voltage | $V_{GS(TH)}$ | -0.4 | _ | -1.0 | V | $V_{DS} = V_{GS}, I_{D} = -250 \mu A$ |
| | | | 51 | 62 | | Vgs = -4.5V, ID = -4.2A |
| Static Drain-Source On-Resistance | R _{DS(ON)} | _ | 71 | 90 | mΩ | VGS = -2.5V, $ID = -3.4A$ |
| | | | 116 | 150 | | VGS = -1.8V, ID = -2.0A |
| Diode Forward Voltage | V_{SD} | _ | -0.7 | -1.1 | V | $V_{GS} = 0V, I_{S} = -1A$ |
| DYNAMIC CHARACTERISTICS (Note 8) | | | | | | |
| Input Capacitance | C _{iss} | _ | 487 | _ | pF | ., |
| Output Capacitance | Coss | _ | 60 | _ | pF | $V_{DS} = -20V, V_{GS} = 0V,$ - f = 1.0MHz |
| Reverse Transfer Capacitance | C _{rss} | _ | 53 | _ | pF | 1 = 1.0WH2 |
| Gate Resistance | R_G | _ | 39 | _ | Ω | $V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$ |
| Total Gate Charge | Q_G | _ | 6.3 | _ | nC | V 4.5V V 4V |
| Gate-Source Charge | Q _{GS} | _ | 0.7 | _ | nC | $V_{GS} = -4.5V, V_{DS} = -4V,$ |
| Gate-Drain Charge | Q_{GD} | _ | 1.4 | _ | nC | $I_D = -3.5A$ |
| Turn-On Delay Time | t _{D(ON)} | _ | 5.3 | _ | ns | |
| Turn-On Rise Time | t _R | _ | 15.7 | _ | ns | $V_{DS} = -4V$, $V_{GS} = -4.5V$, |
| Turn-Off Delay Time | t _{D(OFF)} | _ | 38.5 | _ | ns | $I_D = -1.0A, R_G = 6\Omega$ |
| Turn-Off Fall Time | t _F | _ | 23.2 | _ | ns | |
| Body Diode Reverse Recovery Time | t _{RR} | _ | 7.5 | _ | ns | $I_S = -2.0A$, di/dt = -100A/ μ s |
| Body Diode Reverse Recovery Charge | Q_{RR} | _ | 1.9 | _ | nC | $I_S = -2.0A$, di/dt = -100A/ μ s |

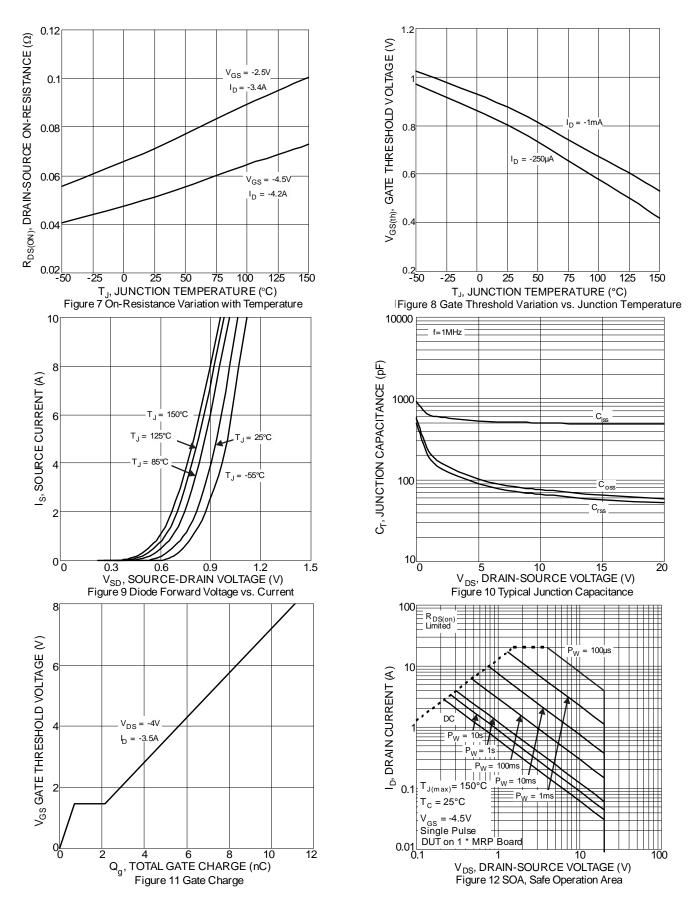
5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

Solution in the district of States (2004). 202 copper, with 1 linch square copper plate.
 Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to product testing.

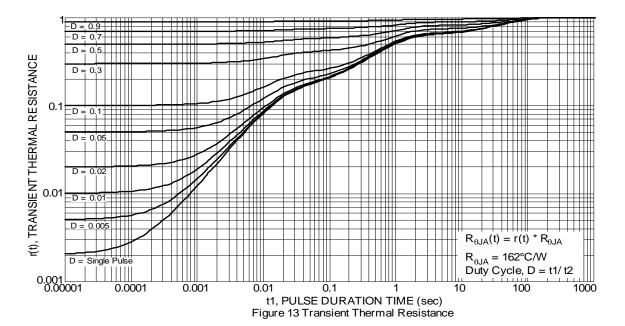








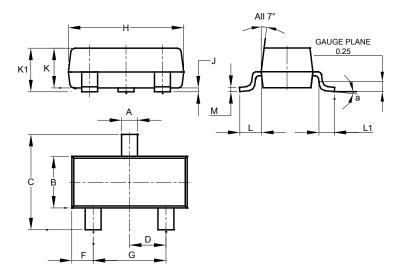






Package Outline Dimensions

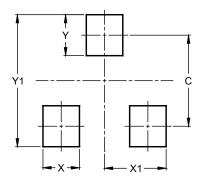
Please see http://www.diodes.com/package-outlines.html for the latest version.



| SOT23 | | | | | | | |
|----------------------|-------|-------|-------|--|--|--|--|
| Dim | Min | Max | Тур | | | | |
| Α | 0.37 | 0.51 | 0.40 | | | | |
| В | 1.20 | 1.40 | 1.30 | | | | |
| С | 2.30 | 2.50 | 2.40 | | | | |
| D | 0.89 | 1.03 | 0.915 | | | | |
| F | 0.45 | 0.60 | 0.535 | | | | |
| G | 1.78 | 2.05 | 1.83 | | | | |
| Η | 2.80 | 3.00 | 2.90 | | | | |
| 7 | 0.013 | 0.10 | 0.05 | | | | |
| K | 0.890 | 1.00 | 0.975 | | | | |
| K 1 | 0.903 | 1.10 | 1.025 | | | | |
| ٦ | 0.45 | 0.61 | 0.55 | | | | |
| L1 | 0.25 | 0.55 | 0.40 | | | | |
| М | 0.085 | 0.150 | 0.110 | | | | |
| а | 0° | 8° | | | | | |
| All Dimensions in mm | | | | | | | |

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| С | 2.0 |
| Х | 0.8 |
| X1 | 1.35 |
| Υ | 0.9 |
| Y1 | 2.9 |



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